Texas Instruments

TPS62843
SLVSFU8 – JANUARY 2022

TPS62843 1.8-V to 5.5-V, 600-mA, 275-nA I$_Q$, Small Size Step-Down Converters

<div style="float:right">ADVANCE INFORMATION</div>

1 Features

- 1.8-V to 5.5-V input voltage range
- 0.4-V to 3.6-V output voltage range
- 275-nA typical quiescent current
- 600-mA output current
- 1% output voltage accuracy
- 20-nA typical shutdown current
- VSET pin-selectable output voltage though a single resistor
  - TPS628436: 0.4 V to 0.8 V
  - TPS628437: 0.8 V to 1.8 V
  - TPS628438: 1.8 V to 3.6 V
- Optimized for small passive components
  - 1-µH inductor
  - Down to 4.7-µF C$_{OUT}$
- Low output voltage ripple in power save mode
- RF-friendly and fast transient DCS-Control
- Automatic transition to no ripple 100% mode
- 0603-inductor and 0402-capacitor size supported
- Tiny 6-pin, 0.35-mm pitch WCSP package with 0.84mm² size
- Pin-to-pin compatible to the TPS6280x family (1 A)

2 Applications

- Wearable electronics
- Headsets/headphones and earbuds
- Mobile phones
- Medical sensor patches
- Hearing aid
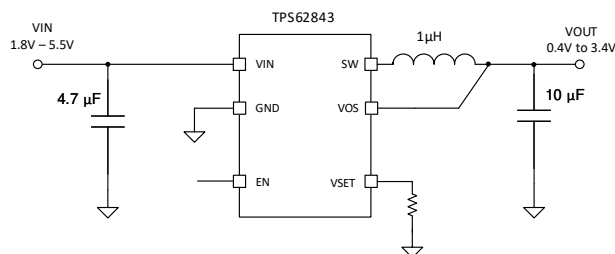
3 Description

The TPS62843 is a high efficiency step-down converter family with ultra-low operating quiescent current of typically 275 nA. It features a 4-nA shutdown (typical) current when disabled.
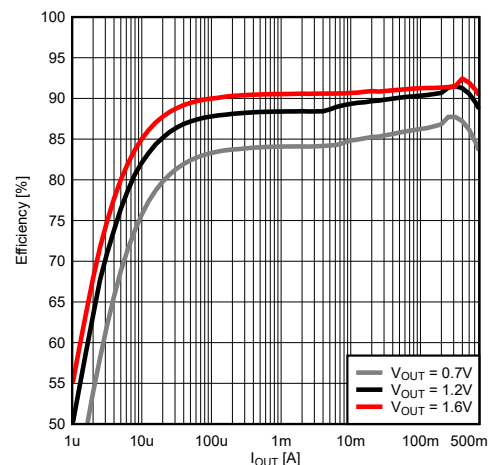
The device uses DCS-Control with a low and RF-friendly output voltage ripple to power radios.

The device operates with a typical switching frequency of 1.5 MHz and extends a high light-load efficiency down to 100-µA load current and below.

18 pre-defined output voltages can be selected by connecting a resistor to the VSET pin, making the family usable across various applications with a minimum set of passive components.

Device Information

Part Number	V$_{OUT}$ Range	Body Size (NOM)
TPS628436	0.4 V–0.8 V	0.8 mm × 1.05 mm × 0.4 mm
TPS628437	0.8 V–1.8 V	0.8 mm × 1.05 mm × 0.4 mm
TPS628438	1.8 V–3.6 V	0.8 mm × 1.05 mm × 0.4 mm

Typical Application

Efficiency vs Output Current at 3.6 V$_{IN}$

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISON	NOTES
January 2022	*	Advance Information

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5 Device Comparison Table

Device	Fixed V_{OUT} VSET = GND	Selectable Output Voltages	f_{SW} [MHz]	Soft Start t_{SS}	Inductor
TPS628436	Reserved	0.4V–0.8V in 25-mV steps	1.5	400 µs	1 µH
TPS628437	1.8 V	0.8V–1.6V in 50-mV steps	1.9	800 µs	1 µH
TPS628438	3.6 V	1.8V–3.4V in 100-mV steps	2.25	800 µs	1 µH

6 Pin Configuration and Functions
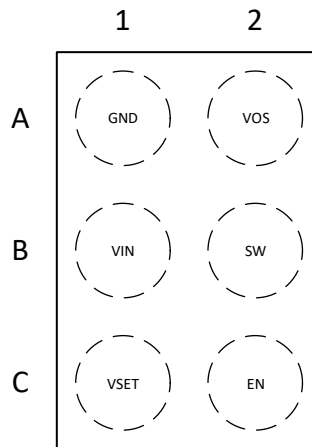
Figure 6-1. 6-Pin DSBGA YKA Package (Top View)

Table 6-1. Pin Functions

PIN NAME	PIN NO.	TYPE	DESCRIPTION
GND	A1	PWR	GND supply pin. Connect this pin close to the GND terminal of the input and output capacitor.
VIN	B1	PWR	V_{IN} power supply pin. Connect the input capacitor close to this pin for best noise and voltage spike suppression. A ceramic capacitor is required.
VSET	C1	I	Connecting a resistor to GND selects a pre-defined output voltage.
VOS	A2	I	Output voltage sense pin for the internal feedback divider network and regulation loop. This pin also discharges V_{OUT} by an internal MOSFET when the converter is disabled. Connect this pin directly to the output capacitor with a short trace.
SW	B2	O	The switch pin is connected to the internal MOSFET switches. Connect the inductor to this terminal.
EN	C2	I	A high level enables the devices and a low level turns the device off. The pin features an internal pulldown resistor, which is disabled once the device has started up.

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7 Specifications

7.1 Absolute Maximum Ratings

Over operating junction temperature range (unless otherwise noted) [1]

		MIN	MAX	UNIT
Pin voltage	VIN	−0.3	6	V
Pin voltage	SW, DC	−0.3	V_{IN} + 0.3 V	V
Pin voltage	SW, transient < 10 ns, while switching	−2.5	9	V
Pin voltage	VIN – SW, DC	—		V
Pin voltage	EN, VSET	−0.3	6	V
Pin voltage	VOS	−0.3	5	V
T_J	Operating junction temperature	−40	150	°C
T_{stg}	Storage temperature	−55	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 [1]	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 [2]	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{IN}	Supply voltage, V_{IN}	1.8		5.5	V
I_{OUT}	Output current			0.6	A
L	Effective inductance	0.7	1.0	1.2	μH
C_{OUT}	Effective output capacitance	4		25	μF
C_{IN}	Effective input capacitance	0.5	4.7		μF
R_{SET}	Resistance range for external resistor at VSET pin (E96 1% resistor values)	4.87		124	kΩ
	External resistor tolerance E96 series at VSET pin			1%	
	E96 resistor series temperature coefficient (TCR)	−200		+200	ppm/°C
T_J	Operating junction temperature range	−40		125	°C

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7.3 Thermal Information

THERMAL METRIC		YKA (DSBGA)	UNIT
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	147.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	1.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	47.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	47.6	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	—	°C/W

7.4 Electrical Characteristics

T_J = –40°C to +125°C, V_{IN} = 1.8 V to 5.5 V. Typical values are at T_J = 25°C and V_{IN} = 3.6 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
I_Q	Operating quiescent current (power save mode)	Nonswitching, V_{EN} = V_{IN}, I_{OUT} = 0 µA, T_J = –40°C to 85°C		275	1500	nA
		Switching, V_{EN} = V_{IN}, I_{OUT} = 0 µA, V_{OUT} = 0.7 V		350		nA
I_{SD}	Shutdown current	V_{EN} = 0 V, VSET = GND, T_J = –40°C to 85°C		4	850	nA
UVLO						
$V_{UVLO(R)}$	Undervoltage lockout rising threshold	V_{IN} rising		1.75	1.8	V
$V_{UVLO(F)}$	Undervoltage lockout rising threshold	V_{IN} falling		1.65	1.7	V
$V_{UVLO(H)}$	Undervoltage lockout hysteresis			100		mV
VSET PIN						
$V_{SET(LKG)}$	VSET input leakage current	T_J = –40°C to 85°C		10	800	nA
$V_{SET(H)}$	VSET high-level detection	Voltage at VSET during start-up	1.0			V
R_{SET}	RSET accuracy		–4%		4%	
ENABLE						
$V_{EN(R)}$	EN voltage rising threshold	EN rising, enable switching	0.8			V
$V_{EN(F)}$	EN voltage falling threshold	EN falling, disable switching			0.4	V
$V_{EN(LKG)}$	EN input leakage current	V_{EN} > 0.8 V, T_J = –40°C to 85°C		1	25	nA
$R_{EN;PD}$	EN internal pulldown resistance	EN pin to GND	425	500		kΩ
VOUT VOLTAGE						
V_{OUT}	DC output voltage accuracy	PWM operation	–1%		+1%	
V_{OUT}	TPS628436		0.4		0.8	V
	TPS628437		0.8		1.8	V
	TPS628438		1.8		3.6	V
$I_{VOS(LKG)}$	VOS input leakage current	TPS628436, V_{EN} = V_{IN}, V_{VOS} = 0.7 V, T_J = –40°C to 85°C				nA
		TPS628437, V_{EN} = V_{IN}, V_{VOS} = 1.2 V, T_J = –40°C to 85°C		100	400	nA
		TPS628438, V_{EN} = V_{IN}, V_{VOS} = 3.3 V, T_J = –40°C to 85°C				nA
f_{SW}	TPS628436	I_{OUT} = 400 mA		1.5		MHz
	TPS628437	I_{OUT} = 400 mA		1.9		MHz
	TPS628438	I_{OUT} = 400 mA		2.25		MHz
STARTUP						
t_{SS}	TPS628436 soft-start time	From V_{OUT}= 0% to V_{OUT}= 95% of V_{OUT} nominal		0.4	0.6	ms
	TPS628438 soft-start time			1.0	1.4	
	TPS628437 soft-start time			0.7	1.0	
	EN HIGH to start of switching delay	R2D = GND		250	460	µs
POWER STAGE						

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7.4 Electrical Characteristics (continued)

T_J = –40°C to +125°C, V_{IN} = 1.8 V to 5.5 V. Typical values are at T_J = 25°C and V_{IN} = 3.6 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{DSON(HS)}$	High-side MOSFET on-resistance	V_{IN} = 3.6 V, I_{OUT} = 300 mA		170	260	mΩ
$R_{DSON(LS)}$	Low-side MOSFET on-resistance	V_{IN} = 3.6 V, I_{OUT} = 300 mA		70	105	mΩ
	Leakage current into the SW pin	V_{SW} = 0.7 V, T_J = –40°C to 85°C		0	25	nA
	Leakage current into the SW pin	V_{SW} = 1.2 V, T_J = –40°C to 85°C		0	25	nA
	Leakage current into the SW pin	V_{VIN} > $V_{SW,}$, V_{SW} = 3.3 V, T_J = –40°C to 85°C		0	30	nA
OVERCURRENT PROTECTION						
$I_{HS(OC)}$	High-side peak current limit	Peak current limit on HS FET	0.9	1.1	1.3	A
$I_{LS(OC)}$	Low-side valley current limit	Valley current limit on LS FET	0.8	1.0	1.1	A
OUTPUT DISCHARGE						
	Output discharge resistor on the VOS pin	V_{EN} = GND, I(VOS) = –10 mA		7	17	Ω
THERMAL SHUTDOWN						
$T_{J(SD)}$	Thermal shutdown threshold	Temperature rising		160		°C
$T_{J(HYS)}$	Thermal shutdown hysteresis			20		°C

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8 Detailed Description

8.1 Overview

The TPS62843 is a high-frequency, synchronous step-down converter with ultra-low quiescent current of typically 275 nA in a 0.84-mm² chip size. The device operates with a tiny 1-µH inductor and 10-µF output capacitor over the entire recommended operation range to provide one of the industry's smallest chip and solution size.

Using TI's DCS-Control topology, the device extends the high efficiency operation area down to microamperes of load current during power save mode operation. TI's DCS-Control (Direct Control with Seamless Transition into power save mode) is an advanced regulation topology that combines the advantages of hysteretic and voltage mode control. Characteristics of DCS-Control are excellent AC load regulation and transient response, low output ripple voltage, and a seamless transition between PFM and PWM mode operation. DCS-Control includes an AC loop that senses the output voltage (VOS pin) and directly feeds the information to a fast comparator stage. This comparator sets the switching frequency, which is constant for steady state operating conditions, and provides immediate response to dynamic load changes. To achieve accurate DC load regulation, a voltage feedback loop is used. The internally compensated regulation network achieves fast and stable operation with small external components and low-ESR capacitors.
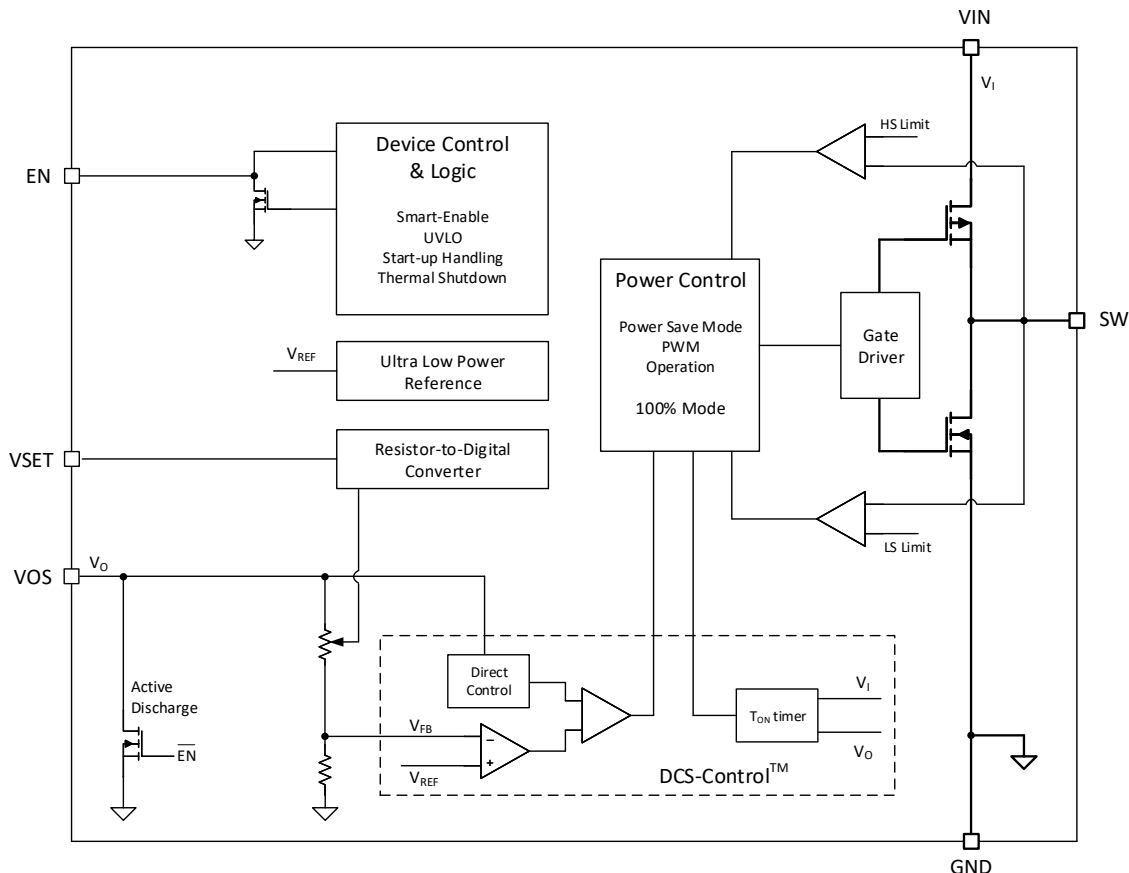
8.2 Functional Block Diagram

Figure 8-1. Functional Block Diagram

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8.3 Feature Description

8.3.1 Smart Enable and Shutdown (EN)

An internal 500-kΩ resistor pulls the EN pin to GND and avoids floating the pin. This prevents an uncontrolled start-up of the device in case the EN pin cannot be driven to low level safely. With EN low, the device is in shutdown mode. The device is turned on with EN set to a high level. The pulldown control circuit disconnects the pulldown resistor on the EN pin once the internal control logic and the reference have been powered up. With EN set to a low level, the device enters shutdown mode and the pulldown resistor is activated again.

8.3.2 Soft Start

Once the device has been enabled with EN high, it initializes and powers up its internal circuits. This occurs during the regulator start-up delay time, $t_{Startup\_delay}$. Once $t_{Startup\_delay}$ expires, the internal soft-start circuitry ramps up the output voltage within the soft-start time, t_{ss}. See Figure 8-2.

The start-up delay time, $t_{Startup\_delay}$, varies depending on the selected VSEL value. It is shortest with VSEL = 0 and longest with VSEL = 16.
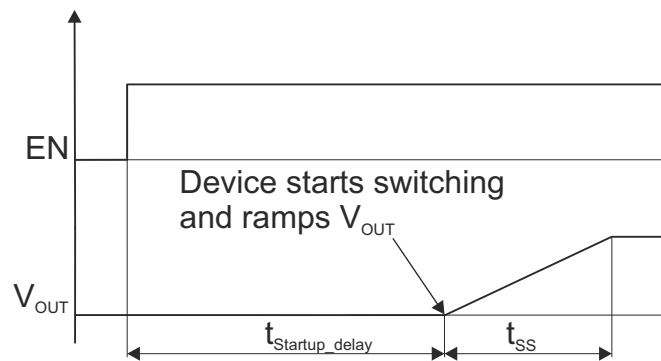
Figure 8-2. Device Start-Up

8.3.3 VSET Pin

This pin is used to define the output voltage selection during start-up of the converter. See Section 5.

8.3.4 VSET Pin: Output Voltage Selection

The output voltage is set with a single external resistor connected between the VSET pin and GND. Once the device has been enabled and the control logic as well as the internal reference have been powered up, a R2D (resistor-to-digital) conversion is started to detect the external resistor, R_{VSET}, within the regulator start-up delay time, $t_{Startup\_delay}$. An internal current source applies current through the external resistor and an internal ADC reads back the resulting voltage level. Depending on the level, an internal feedback divider network is selected to set the correct output voltage. Once this R2D conversion is finished, the current source is turned off to avoid current flow through the external resistor. The circuit can detect resistive values, high-level, low-level, and a pin-open.

For a proper reading, ensure that there is no additional current path or capacitance greater than 30 pF total to GND during R2D conversion. Otherwise, the additional current to GND is interpreted as a lower resistor value and a false output voltage is set. Table 8-1 lists the correct resistor values for R_{VSEL} to set the appropriate output voltages. The R2D converter is designed to operate with resistor values out of the E96 table and requires 1% resistor value accuracy. The external resistor R_{SET} is not a part of the regulator feedback loop and has therefore no impact on the output voltage accuracy. Ensure that there is no other leakage path than the R_{VSET} resistor at the VSET pin during an undervoltage lockout event. Otherwise, a false output voltage is set.

Table 8-1. Output Voltage Setting

VSET	Output Voltage Setting [V]			R_{SET} [Ω]
	TPS628436	TPS628437	TPS628438	
1	0.400	0.80	1.8	10.0 k

Product Folder Links: *TPS62843*

Table 8-1. Output Voltage Setting (continued)

VSET	Output Voltage Setting [V]			R_{SET} [Ω]
	TPS628436	TPS628437	TPS628438	
2	0.425	0.85	1.9	12.1 k
3	0.450	0.90	2.0	15.4 k
4	0.475	0.95	2.1	18.7 k
5	0.500	1.00	2.2	23.7 k
6	0.525	1.05	2.3	28.7 k
7	0.550	1.10	2.4	36.5 k
8	0.575	1.15	2.5	44.2 k
9	0.600	1.20	2.6	56.2 k
10	0.625	1.25	2.7	68.1 k
11	0.650	1.30	2.8	86.6 k
12	0.675	1.35	2.9	105.0 k
13	0.700	1.40	3.0	133.0 k
14	0.725	1.45	3.1	162.0 k
15	0.750	1.50	3.2	205.0 k
16	0.775	1.55	3.3	249.0 k or larger
17	0.8	1.6	3.4	VIN
0	Reserved (contact TI)	1.8	3.6	GND

8.3.5 Undervoltage Lockout (UVLO)

To avoid misoperation of the device at low input voltages, an undervoltage lockout (UVLO) comparator monitors the supply voltage. The UVLO comparator shuts down the device at an input voltage of 1.7 V (maximum) with falling V_{IN}. The device starts at an input voltage of 1.8 V (maximum) rising V_{IN}. Once the device re-enters operation out of an undervoltage lockout condition, it behaves like it does being enabled. The internal control logic is powered up and the external resistor at the VSET pin is read out.

8.3.6 Switch Current Limit/Short Circuit Protection

The TPS62843 integrates a current limit on the high-side and low-side MOSFETs to protect the device against overload or short circuit conditions. The current in the switches is monitored cycle by cycle. If the high-side MOSFET current limit, I_{LIMF} trips, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current. Once the inductor current through the low-side switch decreases beneath the low-side MOSFET current limit, I_{LIMF}, the low-side MOSFET is turned off and the high-side MOSFET turns on again.

8.3.7 Thermal Shutdown

The junction temperature (T_J) of the device is monitored by an internal temperature sensor. If T_J exceeds the thermal shutdown temperature, T_{SD}, of 160°C (typical), the device enters thermal shutdown. Both the high-side and low-side power FETs are turned off. When T_J decreases below the hysteresis amount of typically 20°C, the converter resumes operation, beginning with a soft start to the originally set V_{OUT} (there is no R2D conversion of R_{VSEL}). The thermal shutdown is not active in power save mode.

8.3.8 Output Voltage Discharge

The purpose of the output discharge function is to ensure a defined down-ramp of the output voltage when the device is disabled and to keep the output voltage close to 0 V.

The internal discharge resistor is connected to the VOS pin. The discharge function is enabled as soon as the device is disabled. The minimum supply voltage required to keep the discharge function active is V_{IN} > V_{TH_UVLO}.

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8.4 Device Functional Modes

8.4.1 Power Save Mode Operation

The DCS-Control topology supports power save mode operation. At light loads, the device operates in PFM (pulse frequency modulation) mode that generates a single switching pulse to ramp up the inductor current and recharge the output capacitor, followed by a sleep period where most of the internal circuits are shut down to achieve the lowest operating quiescent current. During this time, the load current is supported by the output capacitor. The duration of the sleep period depends on the load current and the inductor peak current. During the sleep periods, the current consumption is reduced to typically 275 nA. This low quiescent current consumption is achieved by an ultra-low power voltage reference, an integrated high impedance feedback divider network, and an optimized power save mode operation.

In PFM mode, the switching frequency varies linearly with the load current. At medium and high load conditions, the device enters automatically PWM (pulse width modulation) mode and operates in continuous conduction mode with a nominal switch frequency f_{sw} of typically 1.5 MHz (TPS628436), 1.9 MHz (TPS628437), or 2.25 MHz (TPS628438). The switching frequency in PWM mode is controlled and depends on V_{IN} and V_{OUT}. The boundary between PWM and PFM mode is when the inductor current becomes discontinuous.

If the load current decreases, the converter seamlessly enters PFM mode to maintain high efficiency down to very light loads. Since DCS-Control supports both operation modes within one single building block, the transition from PWM to PFM mode is seamless with minimum output voltage ripple.

8.4.2 100% Mode Operation

The duty cycle of the buck converter operating in PWM mode is given as $D = V_{OUT}/V_{IN}$. The duty cycle increases as the input voltage comes close to the output voltage. In 100% duty cycle mode, the device keeps the high-side switch on continuously. The high-side switch stays turned on as long as the output voltage is below the internal set point. This allows the conversion of small input to output voltage differences.

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The following sections discuss the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

9.2 Typical Application
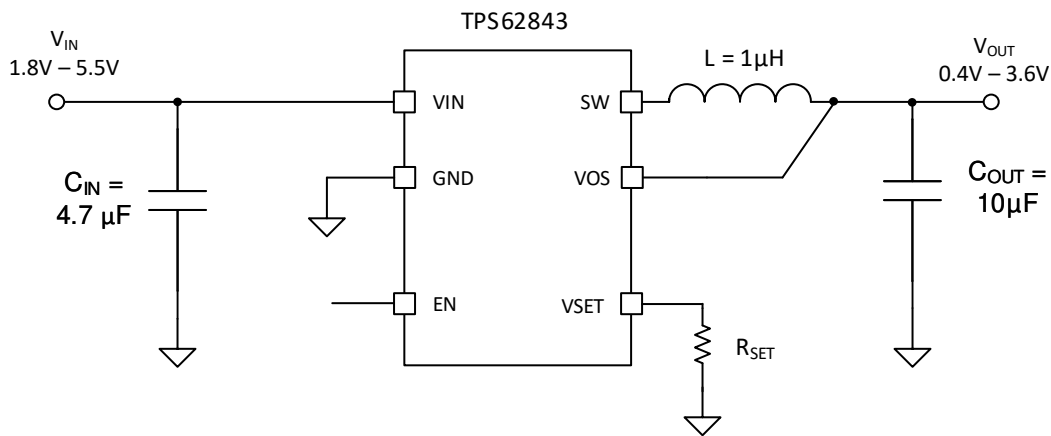
Figure 9-1. TPS62843 Typical Application Circuit

9.2.1 Design Requirements

Table 9-1 shows the list of components for the application circuit and the characteristic application curves.

Table 9-1. Components for Application Characteristic Curves

Reference	Description	Value	Size code Inch [metric L × W × T]	Manufacturer
TPS628436/ TPS628437/ TPS628438	275 nA-I_Q Buck Converter		[1.05 × 0.8 × 0.4 mm]	TI
C_{IN}	Ceramic CapacitorGRM155R60J475ME47D	4.7 µF	0402 [1.0 × 0.5 × 0.5 mm]	Murata
L	InductorDFE201610-1R0M	1 µH	0806 [2.0 × 1.6 × 1.0 mm]	Murata
C_{OUT}	Ceramic Capacitor GRM155R60J106ME15D	10 µF	0402 [1.0 × 0.5 × 0.5 mm]	Murata
R_{SET}	See voltage setting table		0402 [1.0 × 0.5 × 0.5 mm]	

9.2.2 Detailed Design Procedure

Follow the passive component selection per the typical application circuit.

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9.2.3 Application Curves
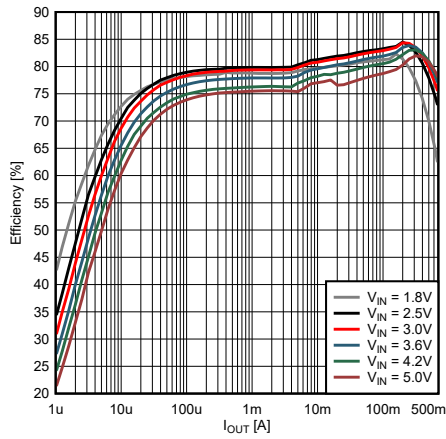
Figure 9-2. Efficiency at 0.4 V$_{OUT}$
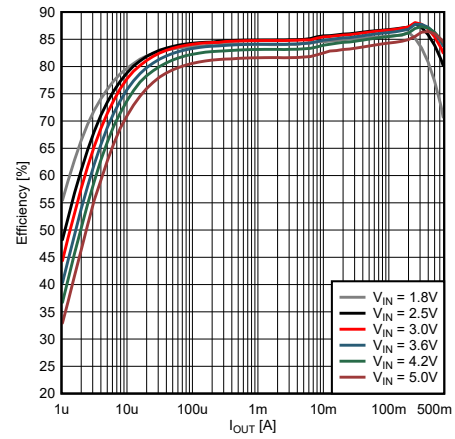
Figure 9-3. Efficiency at 0.7 V$_{OUT}$
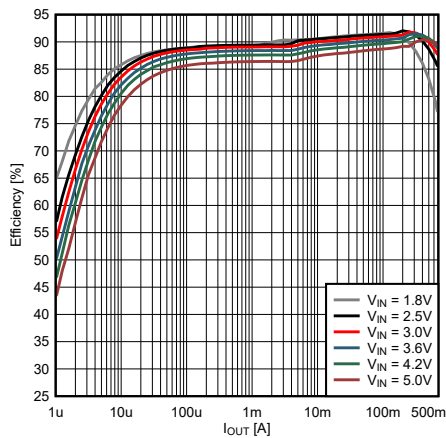
Figure 9-4. Efficiency at 1.2 V$_{OUT}$
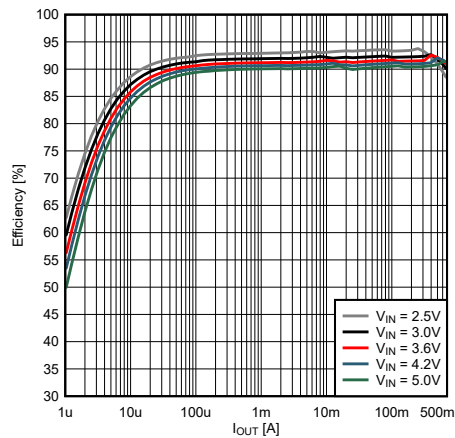
Figure 9-5. Efficiency at 1.8 V$_{OUT}$
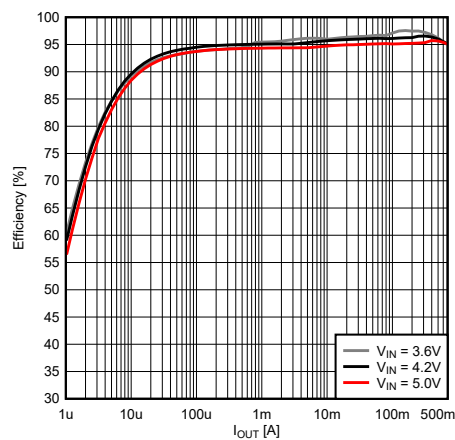

Figure 9-6. Efficiency at 3.3 V$_{OUT}$

Product Folder Links: *TPS62843*

10 Power Supply Recommendations

The power supply must provide a current rating according to the supply voltage, output voltage, and output current of the TPS62843.

11 Layout

11.1 Layout Guidelines

The pinout of TPS62843 has been optimized to enable a single top layer PCB routing of the IC and its critical passive components such as CIN, COUT, and L. Furthermore, this pin out allows the user to connect tiny components such as 0201 (0603) size capacitors and 0402 (1005) size inductors. A solution size smaller than 5 mm^2 can be achieved with a fixed output voltage. As for all switching power supplies, the layout is an important step in the design. Care must be taken in board layout to get the specified performance. It is critical to provide a low inductance, low impedance ground path. Therefore, use wide and short traces for the main current paths. Place the input capacitor as close as possible to the VIN of the IC and GND pins. This is the most critical component placement. The VOS line is a sensitive, high impedance line and must be connected to the output capacitor and routed away from noisy components and traces (for example, the SW line) or other noise sources.

11.2 Layout Example
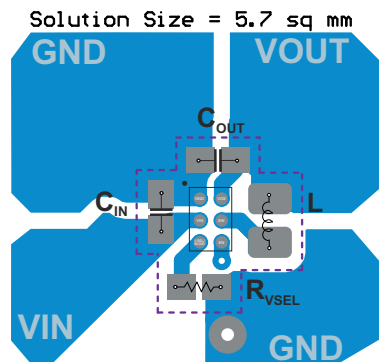
Figure 11-1. Layout Example

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12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

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12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

Product Folder Links: *TPS62843*

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

ADVANCE INFORMATION

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
XPS628436YKAR	ACTIVE	DSBGA	YKA	6	12000	TBD	Call TI	Call TI	-40 to 125		Samples
XPS628437YKAR	ACTIVE	DSBGA	YKA	6	12000	TBD	Call TI	Call TI	-40 to 125		Samples
XPS628438YKAR	ACTIVE	DSBGA	YKA	6	12000	TBD	Call TI	Call TI	-40 to 125		Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
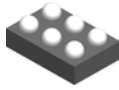
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.
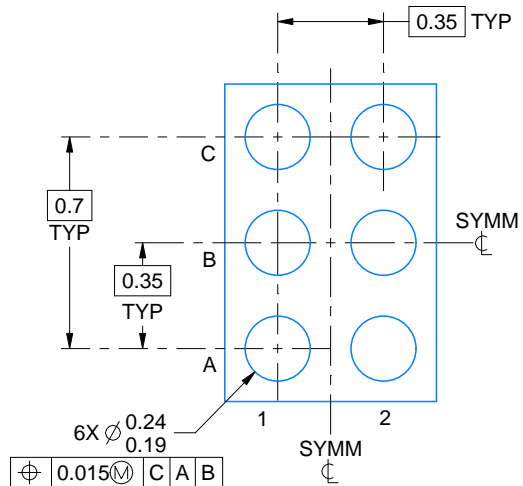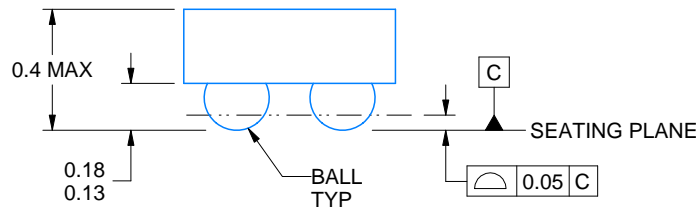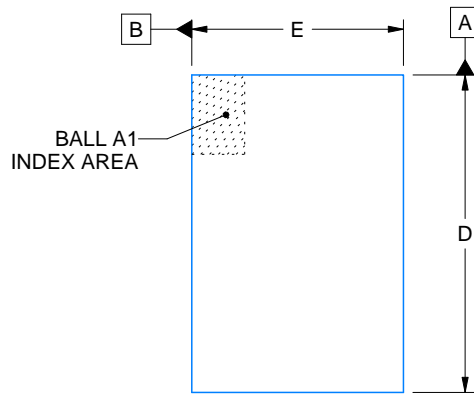
BALL A1 INDEX AREA

B | E | A

D

0.4 MAX

0.18
0.13

BALL TYP

C

SEATING PLANE

0.05 C

0.35 TYP

C

B

A

0.7 TYP

0.35 TYP

SYMM ℄

1   2

SYMM ℄

6X ∅ 0.24
0.19

⊕ | 0.015 Ⓜ | C | A | B

D: Max = 1.04 mm, Min = 0.98 mm

E: Max = 0.787 mm, Min = 0.727 mm

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NanoFree Is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

(0.35) TYP

6X (∅ 0.2)

(0.35) TYP

1   2

A

B   SYMM
                      ℄

C

SYMM
℄
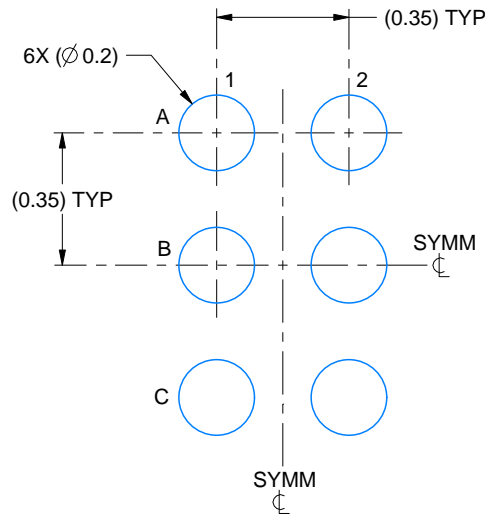
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:50X

(∅ 0.2)
METAL

0.0325 MAX

SOLDER MASK
OPENING

EXSPOSED
METAL

**NON-SOLDER MASK
DEFINED**

0.0325 MIN

METAL
UNDER
SOLDER MASK

EXPOSED
METAL

(∅ 0.2)
SOLDER MASK
OPENING

SOLDER MASK
DEFINED
(PREFERRED)
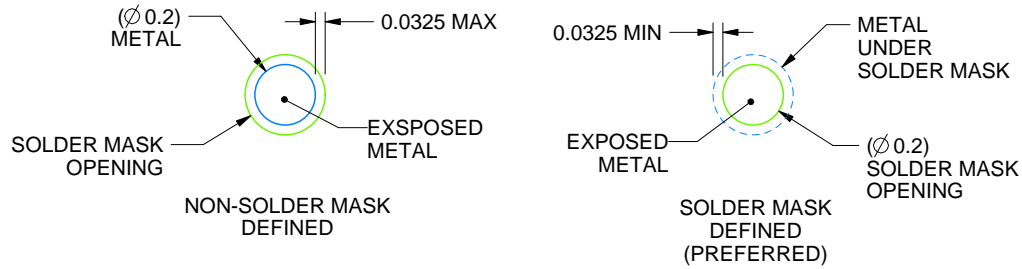
SOLDER MASK DETAILS
NOT TO SCALE

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NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
   For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

(0.35) TYP

6X (☐ 0.21)

(R0.05) TYP

1   2

A

(0.35) TYP

B   SYMM
          ℄

METAL
TYP

C

SYMM
℄
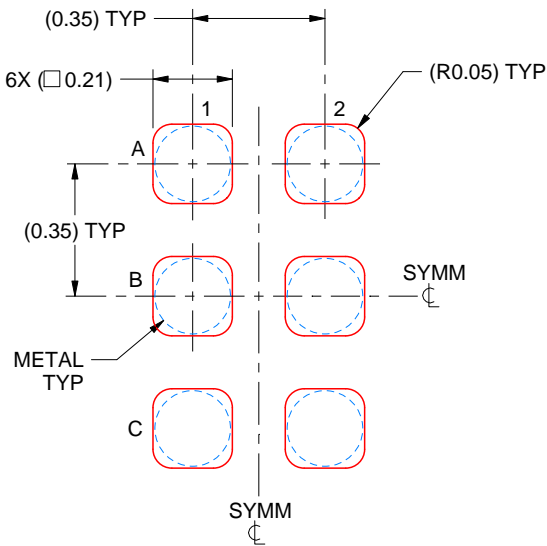
SOLDER PASTE EXAMPLE
BASED ON 0.075 mm - 0.1 mm THICK STENCIL
SCALE:50X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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